MJ15001 (NPN), MJ15002 (PNP)

Complementary Silicon Power Transistors

The MJ15001 and MJ15002 are power transistors designed for high power audio, disk head positioners and other linear applications.

Features

- High Safe Operating Area
- For Low Distortion Complementary Designs
- High DC Current Gain
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	140	Vdc
Collector-Base Voltage	V _{CBO}	140	Vdc
Emitter-Base Voltage	V _{EBO}	5	Vdc
Collector Current – Continuous	۱ _C	15	Adc
Base Current – Continuous	۱ _B	5	Adc
Emitter Current – Continuous	١ _E	20	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	200 1.14	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

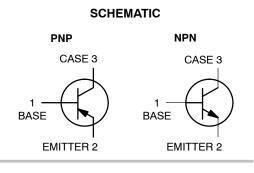
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.875	°C/W
Maximum Lead Temperature for Soldering Purposes $1/16''$ from Case for ≤ 10 secs	ΤL	265	°C



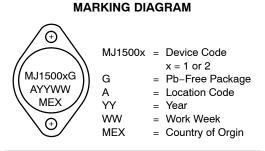
ON Semiconductor®

http://onsemi.com

20 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 140 VOLTS, 250 WATTS







ORDERING INFORMATION

Device	Package	Shipping
MJ15001G	TO-204AA (Pb-Free)	100 Units/Tray
MJ15002G	TO-204AA (Pb-Free)	100 Units/Tray

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Min	Max	Unit
·			•
V _{CEO(sus)}	140	_	Vdc
I _{CEX}		100 2.0	μAdc mAdc
I _{CEO}	-	250	μAdc
I _{EBO}	-	100	μAdc
			•
I _{S/b}	5.0 0.5		Adc
			•
h _{FE}	25	150	-
V _{CE(sat)}	-	1.0	Vdc
V _{BE(on)}	-	2.0	Vdc
fT	2.0	_	MHz
C _{ob}	-	1000	pF
	VCEO(sus) ICEX ICEO IEBO IS/b NFE VCE(sat) VBE(on) fT	$\begin{tabular}{ c c c c } \hline V_{CEO(sus)} & 140 \\ \hline & I_{CEX} & - & - & - & - & - & - & - & - & - & $	$\begin{tabular}{ c c c c } \hline V_{CEO(sus)} & 140 & - & & \\ \hline & I_{CEX} & - & 100 & & \\ \hline & I_{CEO} & - & 250 & & \\ \hline & I_{CEO} & - & 100 & & \\ \hline & I_{EBO} & - & 100 & & \\ \hline & I_{EBO} & - & 100 & & \\ \hline & V_{CE}(sat) & 5.0 & - & & \\ \hline & V_{CE(sat)} & 5.0 & - & & \\ \hline & V_{CE(sat)} & - & 1.0 & & \\ \hline & V_{BE(on)} & - & 2.0 & & \\ \hline & & & & & \\ \hline & & & & & \\ \hline & & & &$

1. Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle \leq 2%.

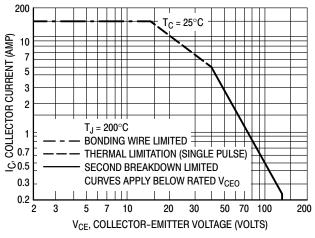
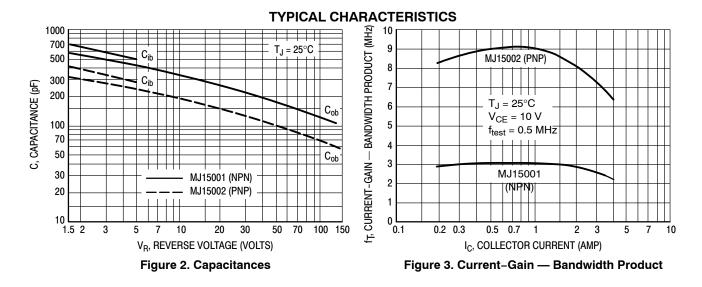


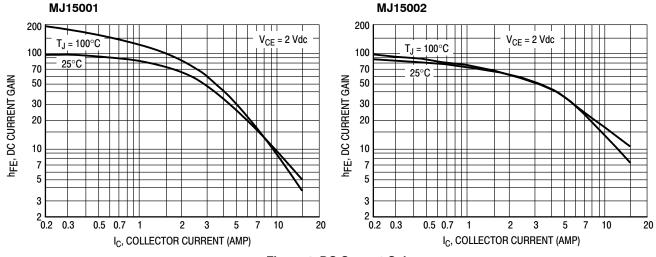
Figure 1. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

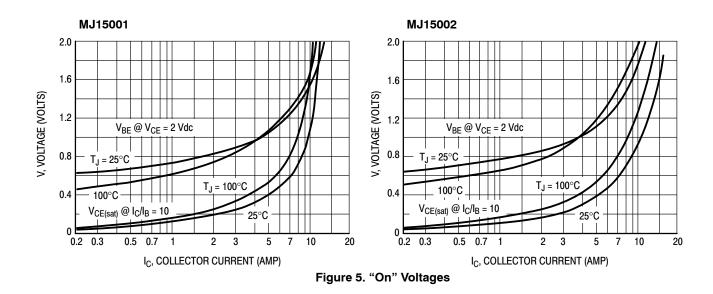
The data of Figure 1 is based on $T_{J(pk)} = 200^{\circ}C$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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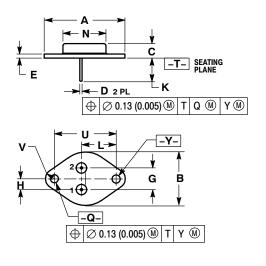






PACKAGE DIMENSIONS

TO-204 (TO-3) CASE 1-07 ISSUE Z



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI
Y14.5M, 1982.

CONTROLLING DIMENSION: INCH.
ALL RULES AND NOTES ASSOCIATED WITH

 ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	1.550 REF		39.37 REF	
В		1.050		26.67
С	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
Е	0.055	0.070	1.40	1.77
G	0.430 BSC 0.215 BSC		10.92 BSC 5.46 BSC	
Н				
Κ	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
Ν		0.830		21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15	BSC
٧	0.131	0.188	3.33	4.77

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

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